Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Metal

**Overall Length:** 

6.500 inches

## **Overall Height:**

0.750 inches

### **Overall Width:**

0.750 inches

# Mounting Facility Quantity:

2

### Mounting Method:

Threaded hole

### Features Provided:

Hermetically sealed case

### **Thread Size:**

0.138 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

40000.0 reverse voltage, peak and 65.0 forward voltage, peak

## **Current Rating Per Characteristic:**

25.00 amperes forward current, average preset

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## **Test Data Document:**

10001-2836190 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unc

# **Terminal Type And Quantity:**

2 turret

Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

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